

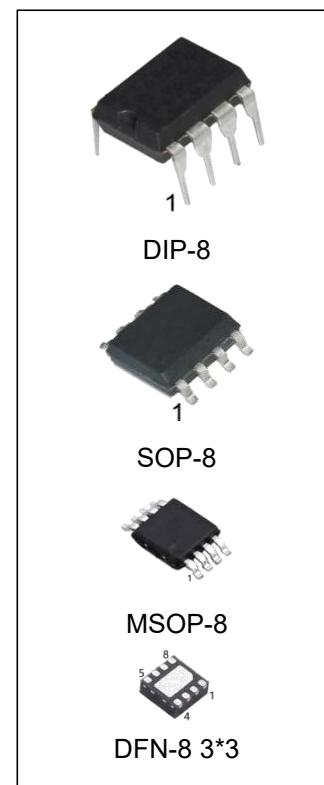
## DUAL OPERATIONAL AMPLIFIER

### DESCRIPTION

JRC4580 is the dual operational amplifier, specially designed for improving the tone control, which is most suitable for the audio application. Featuring noiseless, higher gain bandwidth, high output current and low distortion ratio, and it is most suitable not only for acoustic electronic part of audio pre-amp and active filter, but also for the industrial measurement tools. It is also suitable for the head phone amp at higher output current. And further more, it can be applied for the handy type set operational amplifier of general purpose in application of low voltage single supply type which is properly biased of the input low voltage source.

### FEATURE

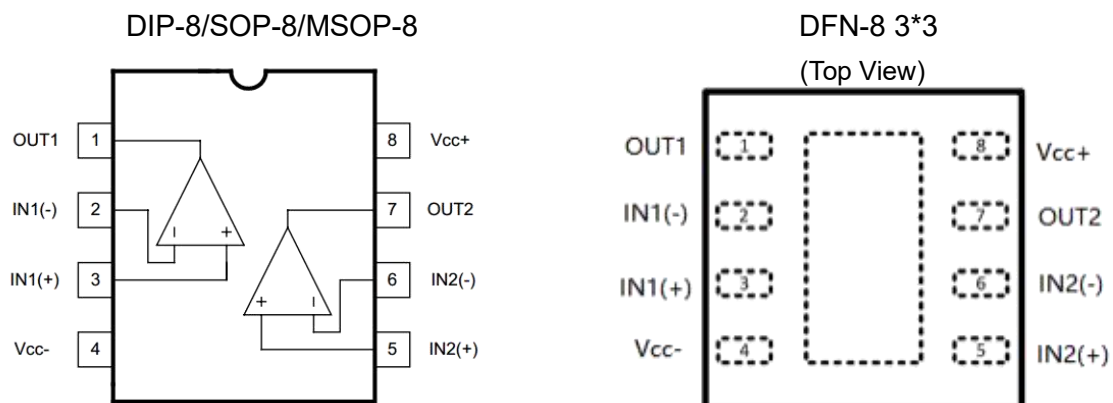
- Operating Voltage:  $\pm 2V \sim \pm 16V$ .
- Low Input Noise Voltage:  $0.8\mu V_{rms}$  Typ.
- Wide Gain Bandwidth Product:  $15MHz$  Typ.
- Low Distortion:  $0.0005\%$  Typ.
- Slew Rate:  $5V/\mu A$  Typ.
- Package Outline DIP-8、SOP-8、DFN-8 and MSOP-8 .
- Bipolar Technology.



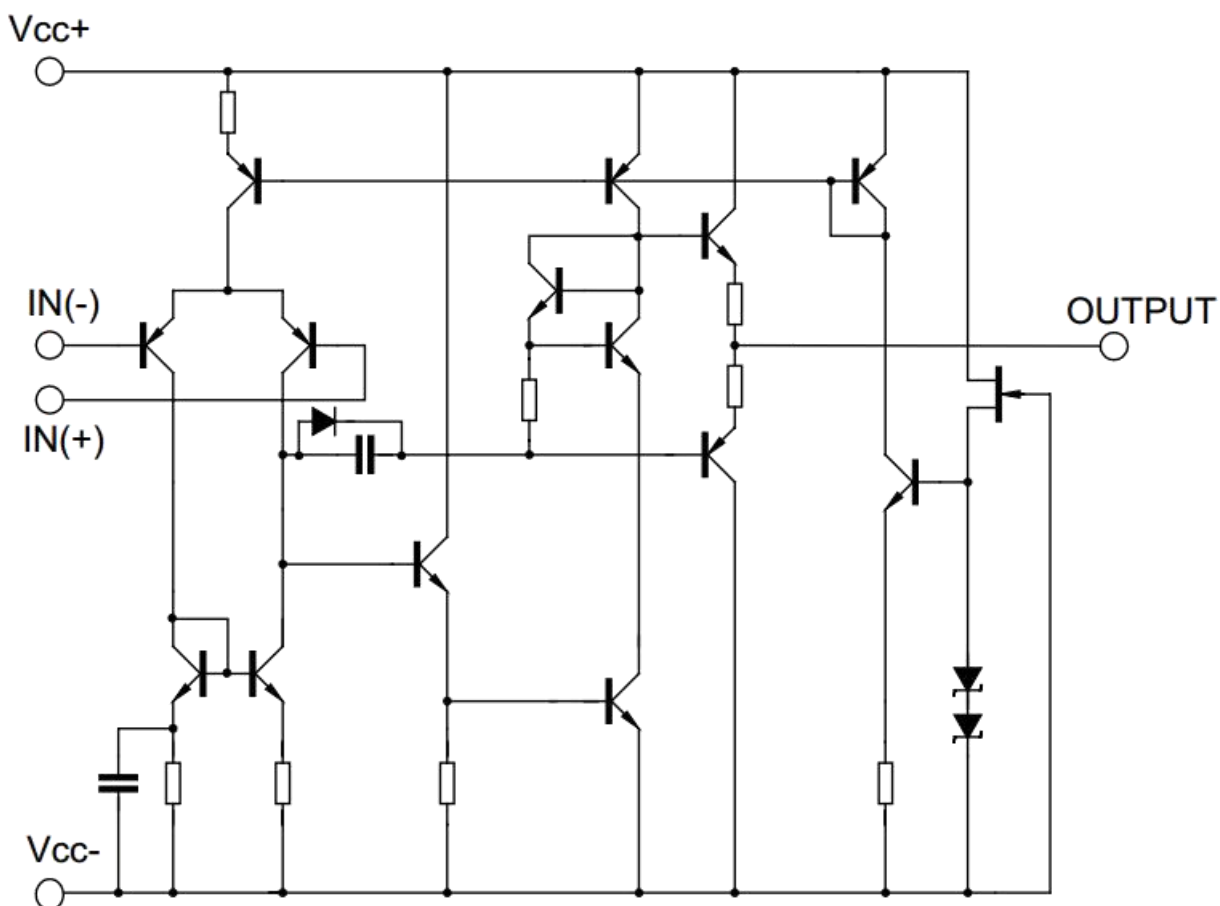
### Ordering Information

| DEVICE       | Package Type | MARKING | Packing | Packing Qty  |
|--------------|--------------|---------|---------|--------------|
| JRC4580PG    | DIP-8        | 4580    | TUBE    | 2000pcs/box  |
| JRC4580DRG   | SOP-8        | 4580    | REEL    | 2500pcs/reel |
| JRC4580DGKRG | MSOP-8       | 4580    | REEL    | 3000pcs/reel |
| JRC4580DQRG  | DFN-8 3*3    | 4580    | REEL    | 5000pcs/reel |

## PIN CONFIGURATION



## EQUIVALENT CIRCUIT



**ABSOLUTE MAXIMUM RATINGS** (Ta=25°C)

| Characteristic                           |        | Symbol           | Value   | Unit |
|--|--------|------------------|---------|------|
| Supply Voltage                           |        | V+/V-            | ±16     | V    |
| Input Voltage                            |        | V <sub>IC</sub>  | ±15     | V    |
| Differential Input Voltage               |        | V <sub>ID</sub>  | ±30     | V    |
| Output Current                           |        | I <sub>O</sub>   | ±50     | mA   |
| Power Dissipation                        | DIP-8  | P <sub>D</sub>   | 800     | mW   |
|  | SOP-8  |                  | 300     |      |
|  | MSOP-8 |                  | 250     |      |
| Operating Temperature Range              |        | T <sub>OPR</sub> | -40~85  | °C   |
| Storage Temperature Range                |        | T <sub>stg</sub> | -40~125 | °C   |
| Lead Temperature (Soldering, 10 seconds) |        | T <sub>L</sub>   | 245     | °C   |

Absolute Maximum Ratings indicate limits beyond which damage to the device may occur. Operating Ratings indicate conditions for which the device is intended to be functional, but specific performance is not ensured.

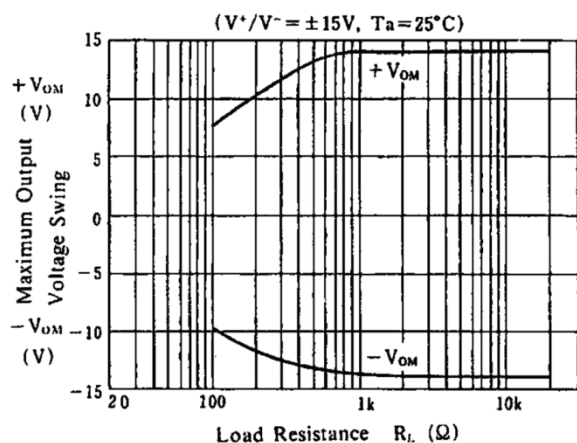
**ELECTRICAL CHARACTERISTICS**

(Unless otherwise specified: Ta= 25°C, V+/V- =±15V)

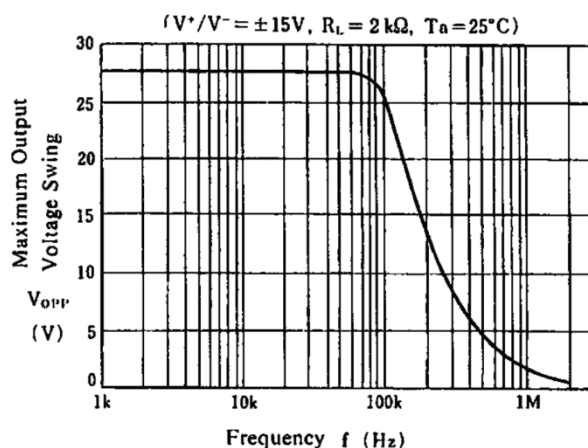
| Parameter                       | Symbol           | Test condition   | Min | Typ    | Max | Unit  |
|---------------------------------|------------------|--|-----|--------|-----|-------|
| Input Offset Voltage            | V <sub>IO</sub>  | R <sub>s</sub> ≤ 10 kΩ   |     | 0.5    | 3   | mV    |
| Input Offset Current            | I <sub>IO</sub>  |  |     | 5      | 200 | nA    |
| Input Bias Current              | I <sub>B</sub>   |  |     | 100    | 500 | nA    |
| Large Signal Voltage Gain       | A <sub>v</sub>   | R <sub>L</sub> ≥ 2kΩ, V <sub>O</sub> = ±10V                                | 90  | 110    |     | dB    |
| Output Voltage Swing            | V <sub>OM</sub>  | R <sub>L</sub> ≥ 2kΩ   | ±12 | ±13.5  |     | V     |
| Input Common Mode Voltage Range | V <sub>ICM</sub> |  | ±12 | ±13.5  |     | V     |
| Common Mode Rejection Ratio     | CMR              | R <sub>s</sub> ≤ 10 kΩ   | 80  | 110    |     | dB    |
| Supply Voltage Rejection Ratio  | SVR              | R <sub>s</sub> ≤ 10 kΩ   | 80  | 110    |     | dB    |
| Operating Current               | I <sub>CC</sub>  |  |     | 6      | 9   | mA    |
| Slew Rate                       | SR               | R <sub>L</sub> ≥ 2kΩ   |     | 5      |     | V/μs  |
| Gain Bandwidth Product          | GB               | f=10kHz  |     | 15     |     | MHz   |
| Total Harmonic Distortion       | THD              | A <sub>v</sub> =20dB, V <sub>O</sub> = 5 V,<br>f=1kHz, R <sub>L</sub> =2kΩ |     | 0.0005 |     | %     |
| Input Noise Voltage             | V <sub>NI</sub>  | RIAA R <sub>s</sub> =2.2kΩ,<br>30kHz LPF                                   |     | 0.8    |     | μVrms |

## CHARACTERISTICS CURVES

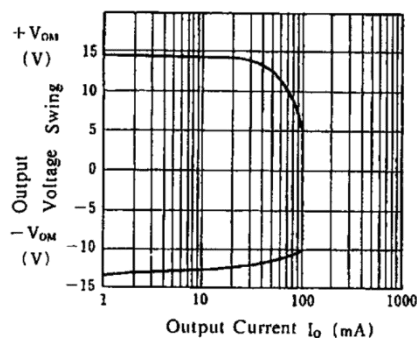
**Maximum Output Voltage Swing vs. Load Resistance**



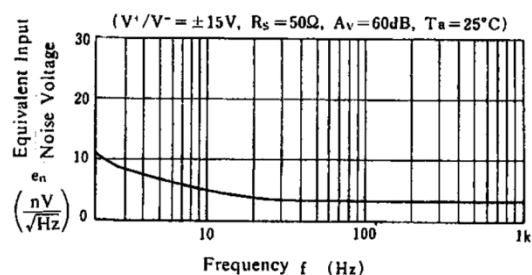
**Maximum Output Voltage Swing vs. Frequency**



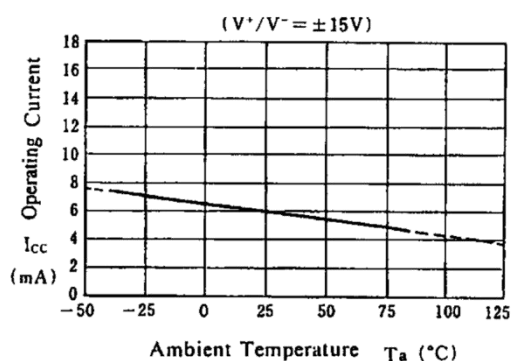
**Output Voltage Swing vs. Output Current**



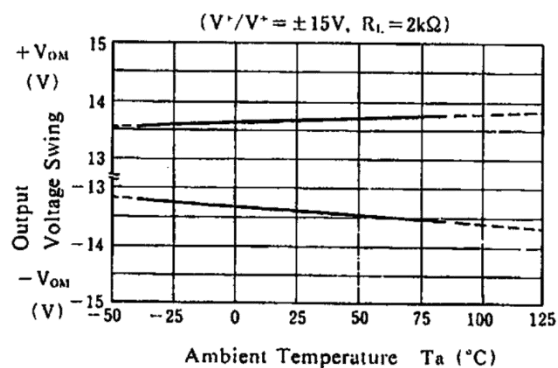
**Equivalent Input Noise Voltage vs. Frequency**



**Operating Current vs. Temperature**

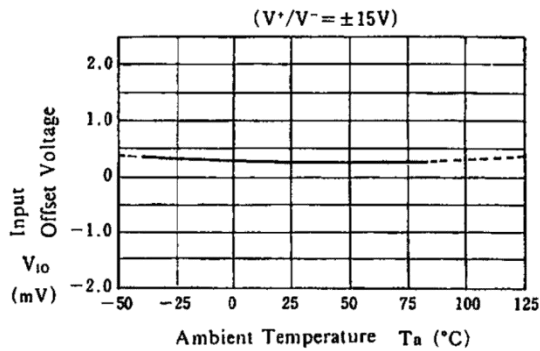


**Output Voltage Swing vs. Temperature**

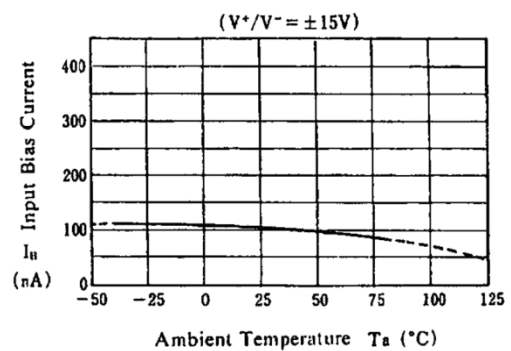


## TYPICAL CHARACTERISTICS

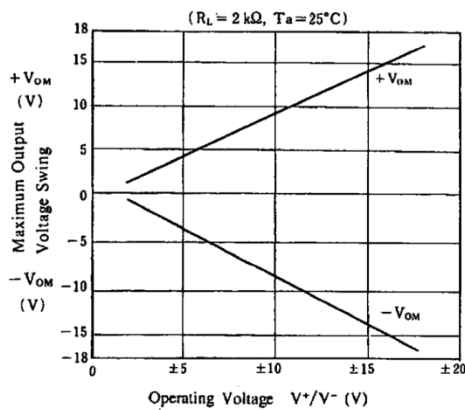
Input offset Voltage vs. Temperature



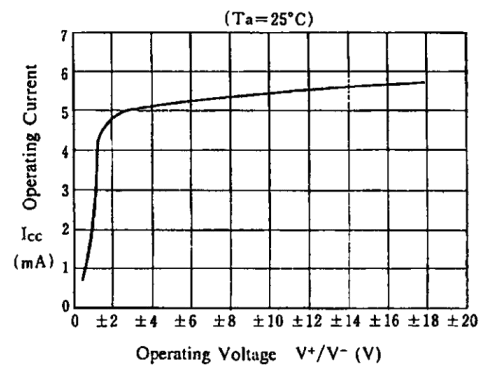
Input bias current vs. Temperature



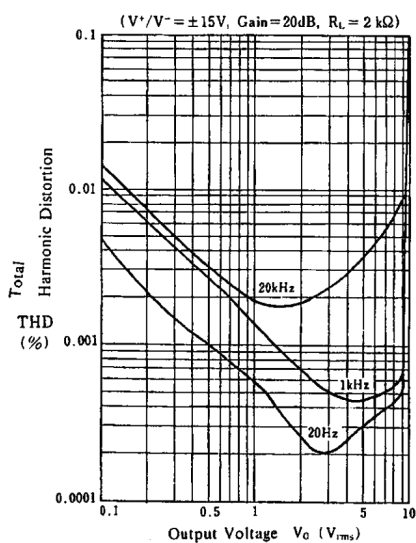
Maximum Output Voltage Swing vs. Operating Voltage



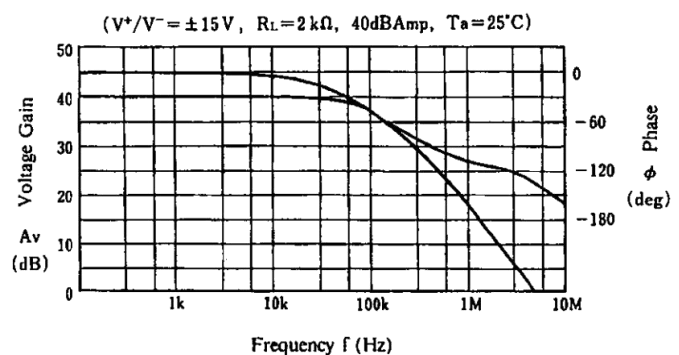
Operating Current vs. Operating Voltage



Total Harmonic Distortion vs. Output Voltage

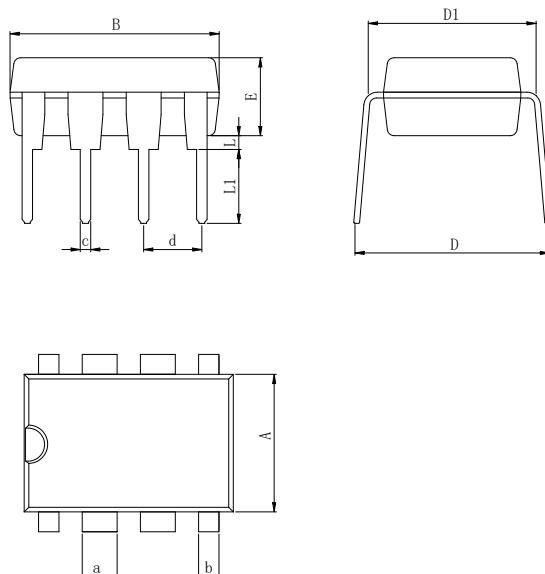


Voltage Gain Phase vs. Frequency



## PHYSICAL DIMENSIONS

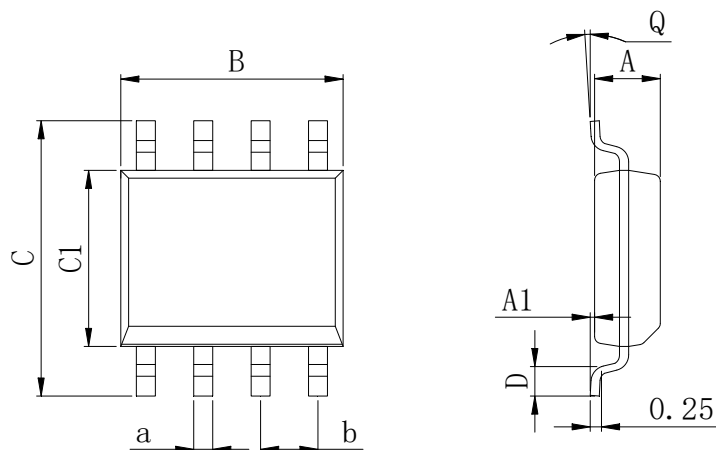
### DIP-8



**Dimensions In Millimeters(DIP-8)**

| Symbol: | A    | B    | D    | D1   | E    | L    | L1   | a    | b    | c    | d        |
|---------|------|------|------|------|------|------|------|------|------|------|----------|
| Min:    | 6.10 | 9.00 | 8.10 | 7.42 | 3.10 | 0.50 | 3.00 | 1.50 | 0.85 | 0.40 | 2.54 BSC |
| Max:    | 6.68 | 9.50 | 10.9 | 7.82 | 3.55 | 0.70 | 3.60 | 1.55 | 0.90 | 0.50 |          |

### SOP-8 (150mil)

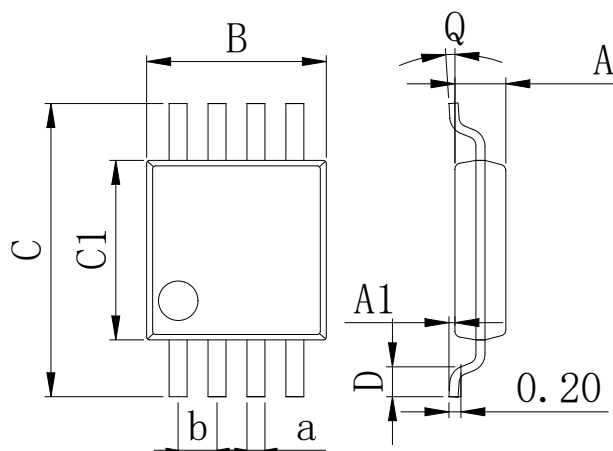


**Dimensions In Millimeters(SOP-8)**

| Symbol: | A    | A1   | B    | C    | C1   | D    | Q  | a    | b        |
|---------|------|------|------|------|------|------|----|------|----------|
| Min:    | 1.35 | 0.05 | 4.90 | 5.80 | 3.80 | 0.40 | 0° | 0.35 | 1.27 BSC |
| Max:    | 1.55 | 0.20 | 5.10 | 6.20 | 4.00 | 0.80 | 8° | 0.45 |          |

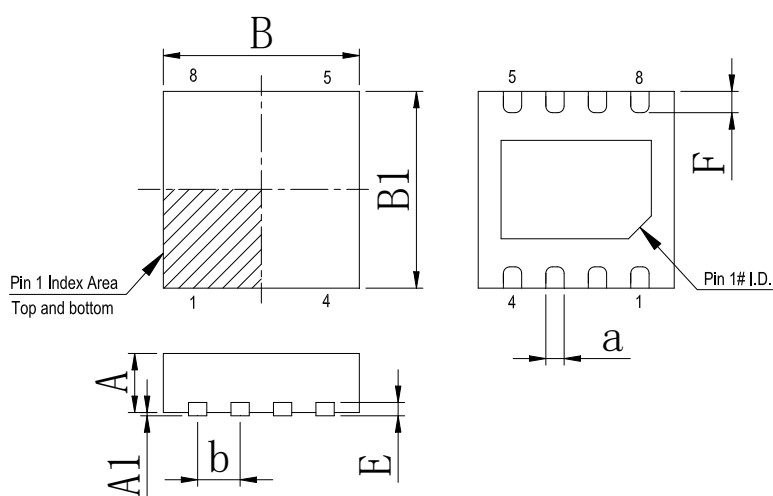
## PHYSICAL DIMENSIONS

### MSOP-8



| Dimensions In Millimeters(MSOP-8) |      |      |      |      |      |      |    |      |          |
|-----------------------------------|------|------|------|------|------|------|----|------|----------|
| Symbol:                           | A    | A1   | B    | C    | C1   | D    | Q  | a    | b        |
| Min:                              | 0.80 | 0.05 | 2.90 | 4.75 | 2.90 | 0.35 | 0° | 0.25 | 0.65 BSC |
| Max:                              | 0.90 | 0.20 | 3.10 | 5.05 | 3.10 | 0.75 | 8° | 0.35 |          |

### DFN-8 3\*3



| Dimensions In Millimeters(DFN-8 3*3) |      |      |      |      |      |      |      |          |
|--------------------------------------|------|------|------|------|------|------|------|----------|
| Symbol:                              | A    | A1   | B    | B1   | E    | F    | a    | b        |
| Min:                                 | 0.85 | 0.00 | 2.90 | 2.90 | 0.20 | 0.30 | 0.20 | 0.65 BSC |
| Max:                                 | 0.95 | 0.05 | 3.10 | 3.10 | 0.25 | 0.50 | 0.34 |          |

**REVISION HISTORY**

| DATE      | REVISION              | PAGE |
|-----------|-----------------------|------|
| 2014-6-23 | New                   | 1-9  |
| 2024-8-20 | Document reformatting | 1-9  |



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